

## **General Description**

The WSP3099 is the highest performance trench P-Ch MOSFET with extreme high cell density , which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The WSP3099 meet the RoHS and Green Product requirement with full function reliability approved.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

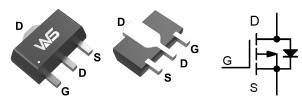
## **Product Summery**

BVDSS	RDSON	ID
-30V	53mΩ	-5.0A

# **Applications**

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

## **SOT-89 Pin Configuration**



# **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	-30	V
$V_{GS}$	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, -V <sub>GS</sub> @ -10V <sup>1</sup>	-5.0	Α
I <sub>D</sub> @T <sub>C</sub> =100℃	Continuous Drain Current, -V <sub>GS</sub> @ -10V <sup>1</sup> -4.0		
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup> -20		А
EAS	Single Pulse Avalanche Energy <sup>3</sup>	18	mJ
I <sub>AS</sub>	Avalanche Current 8		Α
P <sub>D</sub> @T <sub>C</sub> =25℃	Total Power Dissipation <sup>4</sup> 1.8		W
T <sub>STG</sub>	Storage Temperature Range -55 to 150		$^{\circ}$
TJ	Operating Junction Temperature Range -55 to 150		$^{\circ}$

#### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
R <sub>0JA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup>		62.5	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case <sup>1</sup>		30	°C/W



# Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =-250uA	-30			V
$\triangle BV_{DSS}/\triangle T_{J}$	BVDSS Temperature Coefficient	Reference to 25℃ , I <sub>D</sub> =-1mA		-0.02		V/°C
В	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =-10V , I <sub>D</sub> =-5.0A		53	65	0
R <sub>DS(ON)</sub>		V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-3.8A		80	98	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> . I <sub>D</sub> =-250uA	-1.0	-1.5	-2.0	V
$\triangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =-250UA		4.32		mV/℃
	Drain Source Leakage Current	$V_{DS}$ =-24V , $V_{GS}$ =0V , $T_J$ =25 $^{\circ}$ C			-1	uA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =-24V , V <sub>GS</sub> =0V , T <sub>J</sub> =55℃			-5	
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20V$ , $V_{DS}$ = $0V$			±100	nA
gfs	Forward Transconductance	$V_{DS}$ =-5V , $I_{D}$ =-3A		5.5		S
$R_g$	Gate Resistance	V <sub>DS</sub> =0V , V <sub>GS</sub> =0V , f=1MHz		24	48	Ω
$Q_g$	Total Gate Charge (-4.5V)	V <sub>DS</sub> =-15V , V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-5A		11.6		
$Q_gs$	Gate-Source Charge			1.3		nC
Q <sub>gd</sub>	Gate-Drain Charge			2.5		
$T_{d(on)}$	Turn-On Delay Time			6	12	
T <sub>r</sub>	Rise Time	$V_{DD}$ =-15V, $V_{GEN}$ =-10V, $R_{G}$ =3.3 $\Omega$		12	23	200
T <sub>d(off)</sub>	Turn-Off Delay Time	I <sub>D</sub> =-1A ,R <sub>L</sub> =15Ω		25	46	ns
T <sub>f</sub>	Fall Time			6	12	1
Ciss	Input Capacitance	V <sub>DS</sub> =-15V , V <sub>GS</sub> =0V , f=1MHz		625		
C <sub>oss</sub>	Output Capacitance			100		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			60		

### **Guaranteed Avalanche Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy <sup>5</sup>	V <sub>DD</sub> =25V , L=0.1mH , I <sub>AS</sub> =6A	6			mJ

### **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I <sub>S</sub>	Continuous Source Current <sup>1,6</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			-2.0	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,6</sup>				-20	Α
V <sub>SD</sub>	Diode Forward Voltage <sup>2</sup>	V <sub>GS</sub> =0V , I <sub>S</sub> =-1.7A , T <sub>J</sub> =25℃			-1	V

#### Note

- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper,t<10sec.
- 2.The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%
- 3. The EAS data shows Max. rating . The test condition is  $V_{DD}$ =-25V,  $V_{GS}$ =-10V, L=0.1mH,  $I_{AS}$ =-6A
- 5.The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



# **Typical Characteristics**

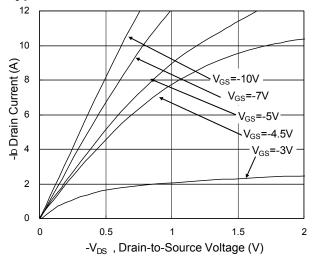
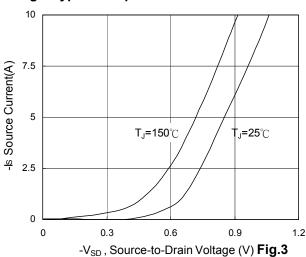


Fig.1 Typical Output Characteristics



**Forward Characteristics of Reverse** 

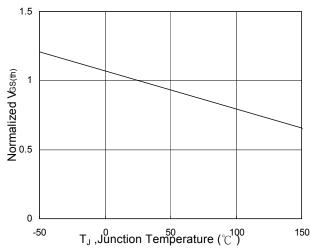


Fig.5 Normalized V<sub>GS(th)</sub> vs. T<sub>J</sub>

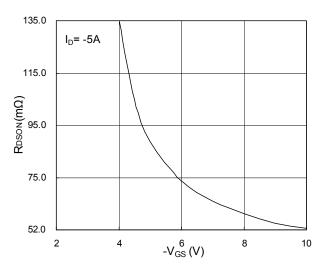


Fig.2 On-Resistance vs. G-S Voltage

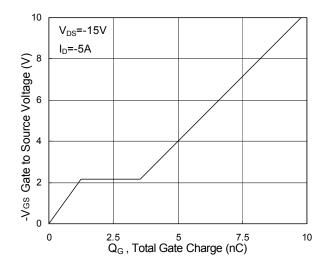


Fig.4 Gate-Charge Characteristics

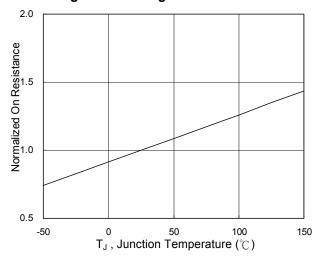
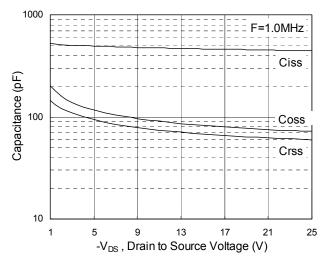


Fig.6 Normalized R<sub>DSON</sub> vs. T<sub>J</sub>





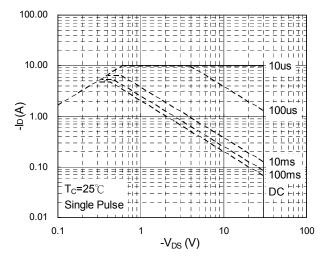


Fig.7 Capacitance

Fig.8 Safe Operating Area

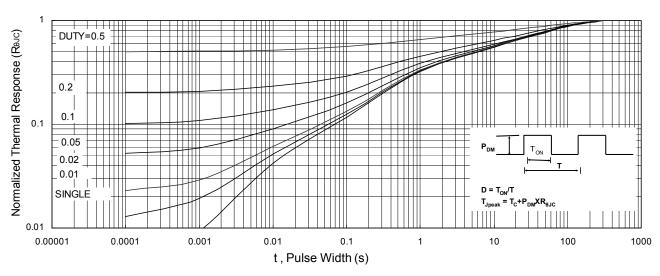


Fig.9 Normalized Maximum Transient Thermal Impedance

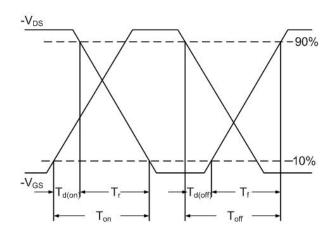


Fig.10 Switching Time Waveform

Fig.11 Unclamped Inductive Waveform



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